

GL9□ 18 GL8□ 18 Series

45.0mm Character Height
Numeric LEDs

■ Model No.

GL9L18/GL8L18
GL9D18/GL8D18
GL9E18/GL8E18

Red (High-luminosity)
Red
Yellow-green

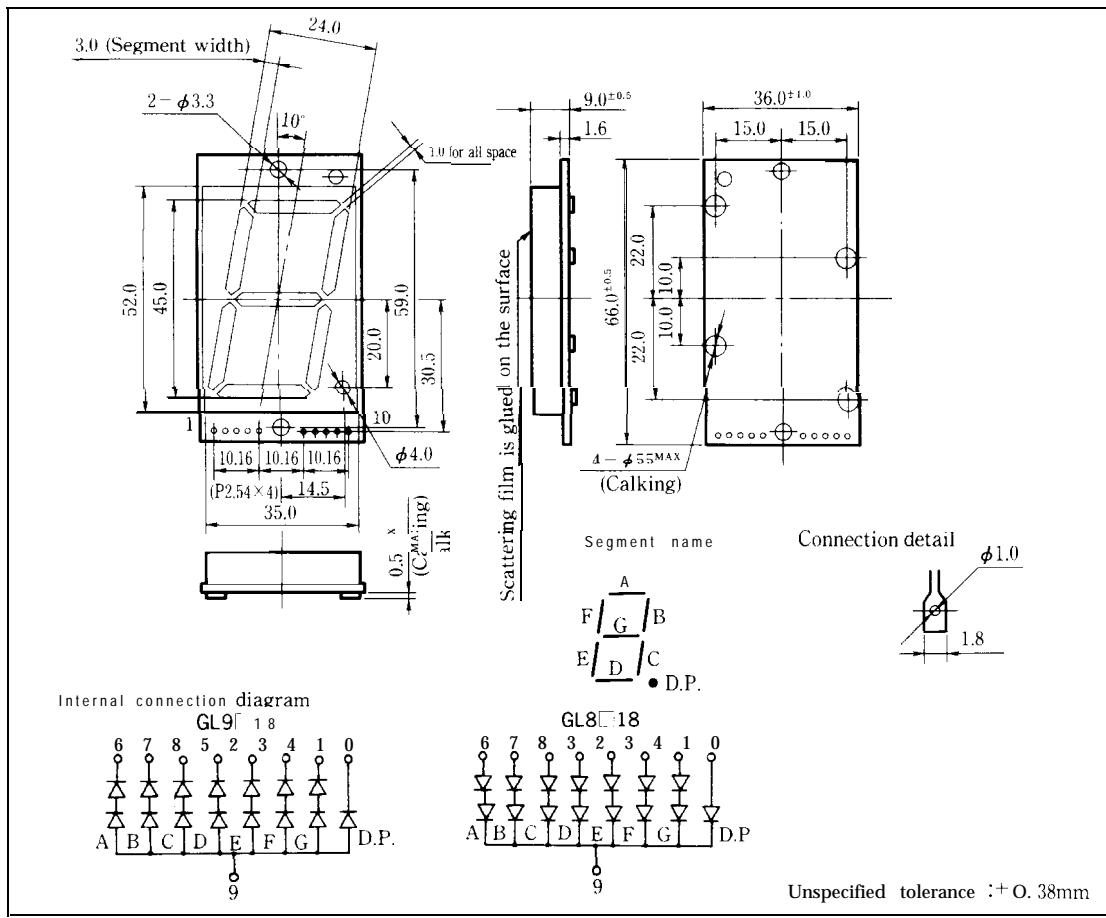
GaAlAs/GaAs
GaAsP/GaP
GaP

■ Features

1. Character height : 45.0mm
2. 1 digit
3. Substrate type

■ Outline Dimensions

(Unit: mm)



GL9□ 18 / GL8□ 18**■ Absolute Maximum Ratings**

(Ta = 25°C)

Parameter	Symbol	GL9L18	GL9D18	GL9E18				Unit
		GL8L18	GL8D18	GL8E18				
Power dissipation	*1 Per digit	P	1,540	1,176	700			mVV
Continuous forward current	*1 Per digit	I _F	350	210	140			mA
	*2	I _F	50	30	20			mA
*3 Peak forward current	*2	I _{FM}	300	50	50			mA
Derating factor	*1 Per digit	DC	—	7.78	4.67	3.11		mA/°C
		Pulse	—	46.7	7.78	7.78		mA/°C
Reverse voltage	Per segment	V _R	5	5	5			V
	Per decimal point	V _R	5	5	5			v
Operating temperature	T _{opr}			−10	to	+60		“c
Storage temperature	T _{stg}			−20 to +70				“c
Soldering temperature	T _{sol}			260 (within 5 seconds)				“c

※1 Per digit: 7 segments

※2 Per segment, or per decimal point

※3 Duty ratio = 1/10, Pulse width = 0.1ms

Duty ratio = 1/16, Pulse width \leq 1ms for GL9L18/GL8L18

GL9L18/GL8L18(Red)

■ Electro-optical Characteristics

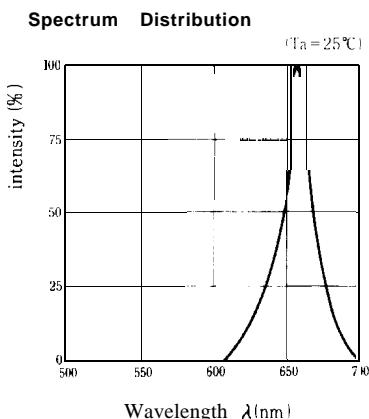
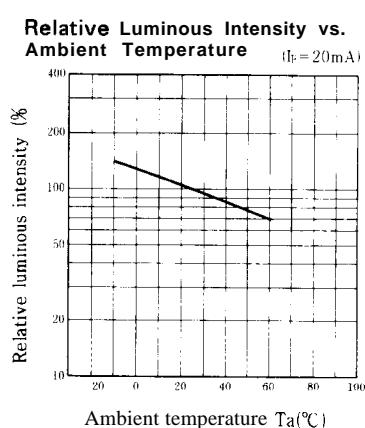
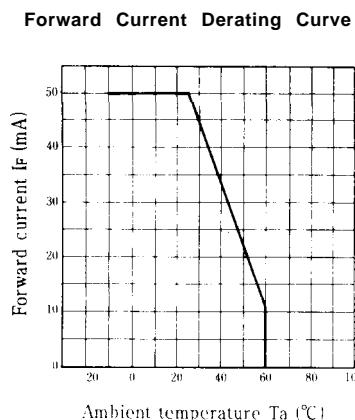
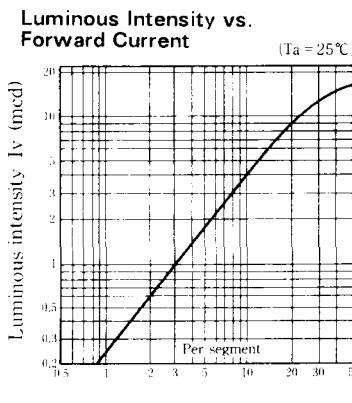
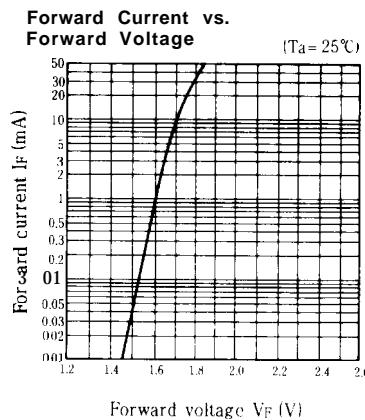
(Ta = 25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL9L18/GL8L18	I _F = 20mA		3.5	4.4	V
		GL9L18/GL8L18	I _F = 20mA		1.75	2.20	V
*5 Luminous intensity	I _V	GL9L18/GL8L18	I _F = 20mA	3.6	9.0	—	mcd
		GL9L18/GL8L18	I _F = 20mA	1.02	2.55	—	mcd
*2 Peak emission wavelength	λ _p	GL9L18/GL8L18	I _F = 20mA	—	660	—	*m
*2 Spectrum radiation bandwidth	Δλ	GL9L18/GL8L18	I _F = 20mA	—	20	—	nm
Reverse current	I _R	GL9L18/GL8L18	V _R = 4V	—	—	10	μA
		GL9L18/GL8L18	V _R = 4V	—	—	10	μA
*2 Response frequency	f _c	GL9L18/GL8L18	—	—	8	—	MHz

*2 Per segment, or per decimal point

*5 Tolerance: ±30%

■ Characteristics Diagrams



GL9D18/GL8DI 8(Red)

■ Electro-optical Characteristics

(Ta=25°C)

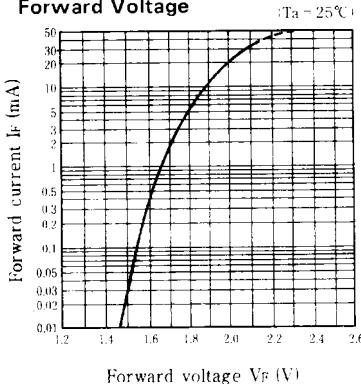
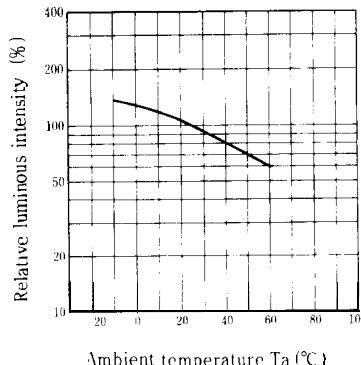
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	Per segment V _F	GL9D18/GL8D18	I _F =20mA	—	4.0	5.6	V
	Per decimal point	GL9D18/GL8D18	I _F =20mA	—	2.0	2.8	V
*5 Luminous intensity	Per segment I _V	GL9D18/GL8D18	I _F =20mA	2.2	6.4	—	mcd
	Per decimal point	GL9D18/GL8D18	I _F =20mA	0.6	1.8	—	mcd
*2 Peak emission wavelength	λ _p	GL9D18/GL8D18	I _F =20mA	—	635	—	nm
*2 Spectrum radiation bandwidth	Δλ	GL9D18/GL8D18	I _F =20mA	—	35	—	nm
Reverse current	Per segment I _R	GL9D18/GL8D18	V _R =4V	—	—	10	μA
	Per decimal point	GL9D18/GL8D18	V _R =4V	—	—	10	μA
*2 Response frequency	f _c	GL9D18/GL8D18	—	—	4	—	MHz

*2 Per segment, OR per decimal point

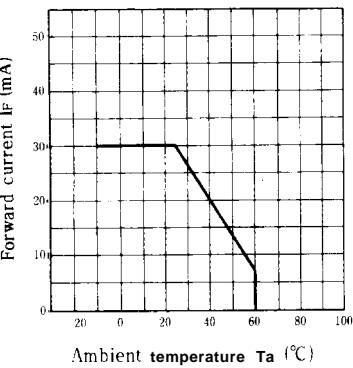
*5 Tolerance: ±30%

■ Characteristics Diagrams

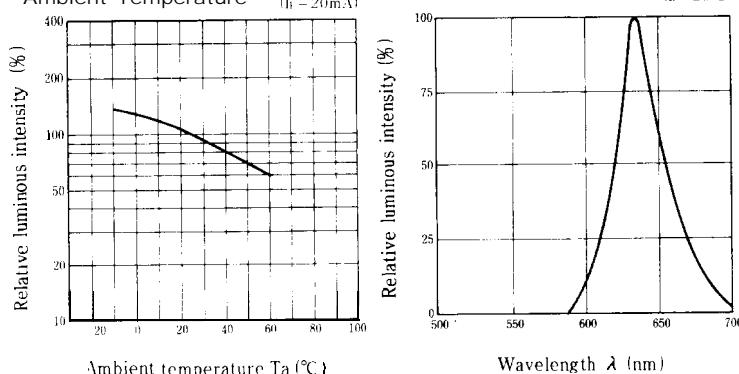
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Forward Current vs.
Forward VoltageRelative Luminous Intensity vs.
Ambient Temperature (If = 20mA)Luminous Intensity vs.
Forward Current

Forward Current Derating Curve



Spectrum Distribution



SHARP

GL9E18/GL8E18{ Yellow-green}

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	Per segment V _F	GL9E18/GL8E18	I _F = 10mA		4.0	5.0	V
		GL9E18/GL8E18	I _F = 10mA		2.0	2.5	V
*5 Luminous intensity	Per segment I _V	GL9E18/GL8E18	I _F = 10mA	1.9	3.4	—	mcd
		GL9E18/GL8E18	I _F = 10mA	0.5	1.0	—	mcd
*2 Peak emission wavelength	λ _p	GL9E18/GL8E18	I _F = 10mA	—	565	—	nm
*2 Spectrum radiation bandwidth	Δλ	GL9E18/GL8E18	I _F = 10mA	—	30	—	nm
Reverse current	Per segment I _R	GL9E18/GL8E18	V _R = 4V	—	—	10	μA
		GL9E18/GL8E18	V _R = 4V	—	—	10	μA
*2 Response frequency	f _c	GL9E18/GL8E18	—	—	4	—	MHz

*2 Per segment, or per decimal point

*5 Tolerance: ±30%

■ Characteristics Diagrams

